## Exploring a subsurface in metals with STM

O. Kurnosikov



o.kurnosikov@tue.nl

## Introduction: Scanning Tunneling Microscopy/Spectroscopy



Mismatch of crystalline lattices of substrate and impurity atoms or embedded nanocluster .

## **Relief variation**



Co nanoclusters embedded below Cu(001) surface, 75 x 75 nm  $^{2}$ .

Relaxation of crystalline lattice and interaction of embedded atoms





Ar bubble below Cu(001) surface,  $30 \times 15$  nm<sup>2</sup>.

# Buried nanocavities and clusters: TU/e results



Ar-, Ne- or He- filled nanocavities have much stronger scattering effect and therefore they can be detected much dipper than single impurities atoms. The nanocavities are visualized in STM measurements as spots of different contrast above their locations. The contrast oscillates with bias. From the oscillation period the depth can be deduced. Different facets of nanocavities induce different oscillation phase and period. From this the shape and size of the nanocavity can be determined.



### Shape: different spots – different facets





### Ar nanocavities in Cu(001), the same area, different bias





What we have and what we see





600mV 500mV 60×60 nm<sup>2</sup> Ar nanocavities in Cu(110), the same area, different bias









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400mV

 $\frac{\pi}{\Delta E} \frac{\partial E}{\partial \mathbf{k}}$ 

d =

60×60 nm<sup>2</sup>

500mV



# Ultimate depth detection: nanocavities in Cu(110) – 80 nm

Depth



# 4.5 nm 12.5 nm 22.4 nm 32.5 nm 39.0 nm 52.9 nm 62.8 nm 80.0 nm 20 x 20 nm<sup>2</sup>

### **Applications**





### For micro- nanolithography

For ITER

Ar, Ne, He implantation defects in conducting layers (Al, Cu, Au, Ag, ...) during plasma processing or magnetron sputtering deposition

Degradation of W or Mo walls by implantation and growth of H<sub>2</sub> and

He-filled nanocavities: the growth of nanicavities can be visualizeed



### For clean material technology

TU

Study near-surface defects and interfaces directly or by decoration them with He or H nanocavities

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(e)	20 nm	(f) 20 nm
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(q)	20 nm	(h) 20 nm

For solar cells and nanophotonics Ge nanoclusters and nanovoids in fused silica

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### Application for ITER: Shape of nanocavity in W

#### **Possible Wulf constructions** Tungsten with impurities Pure tungsten (221) (310) (211) (001) (111) (211) (111) (310) (011) **(b)** (010) $(01\bar{1})$ [**1**10] $\mathbf{1}$ (A): W (B): W+Ba [110] (**d**) (210) (110) (011) 11 **101**) (010 011) (011) (110) $(\bar{1}00)$ (D): W+Ba+O (C): W+O R. Kositski, D. Mordehai / Acta Materialia 90 (2015) 370-379 R. Jacobs, D. Morgan, and J. Booske ArXiv 1712.05308.pdf

